

30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON) max}	I _{D max} T _A = +25°C
30V	$17m\Omega$ @ $V_{GS} = 10V$	8.4A
30 V	28mΩ @ V _{GS} = 4.5V	6.8A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions

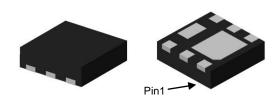
Features

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

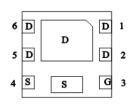
Mechanical Data

- Case: U-DFN2020-6 (Type F)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 64
- · Weight: 0.0065 grams (Approximate)

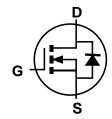
U-DFN2020-6 (Type F)



Top View Bottom View



Pin Out Bottom View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging		
DMT3020LFDF-7	U-DFN2020-6 (Type F)	3,000/Tape & Reel		
DMT3020LFDF-13	U-DFN2020-6 (Type F)	10,000/Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

U-DFN2020-6 (Type F)



Y1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2015		2016	2017		2018	2019		2020	2021		2022
Code	С		D	Е		F	G		Н	ı		J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code			_			_	_			^	N	



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10.0V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I _D	8.4 6.7	А
Continuous Drain Current (Note 6) V _{GS} = 4.5V	I _D	6.8 5.4	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	40	Α		
Maximum Body Diode Continuous Current (Note 6)	Is	2	Α		
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	11.4	Α		
Avalanche Energy (Note 7) L = 0.1mH	Eas	6.5	mJ		

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	Б	0.7	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	P_{D}	0.4	VV
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	180	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	D-	1.8	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	P_{D}	1.1	VV
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	70	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	30.0	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	1	_	1.0	μΑ	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						•
Gate Threshold Voltage	V _{GS(TH)}	1.0	_	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
Static Drain-Source On-Resistance			13	17	mΩ	$V_{GS} = 10V, I_D = 9.0A$
Static Dialii-Source Off-Resistance	R _{DS(ON)}		21	28	11122	$V_{GS} = 4.5V, I_D = 7.0A$
Diode Forward Voltage	V _{SD}	_	_	1.2	V	$V_{GS} = 0V$, $I_S = 2A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	_	393	_	pF	45)/)/ 6)/
Output Capacitance	Coss	_	173	_	pF	$V_{DS} = 15V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	27	_	pF	1 = 1.000112
Gate Resistance	Rg	_	1.1	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	_	7.0	_	nC	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	3.6	_	nC	\/ 45\/ L 00
Gate-Source Charge	Qgs	_	0.9	_	nC	$V_{DD} = 15V, I_{D} = 9A$
Gate-Drain Charge	Q_{gd}	_	1.5	_	nC	
Turn-On Delay Time	t _{D(ON)}	_	1.8	_	ns	
Turn-On Rise Time	t _R	_	1.9	_	ns	$V_{DD} = 15V, V_{GS} = 10V,$
Turn-Off Delay Time	t _{D(OFF)}	_	7.5	_	ns	$R_G = 6\Omega$, $I_D = 9A$
Turn-Off Fall Time	t _F	_	2.4	_	ns	
Reverse Recovery Time	t _{RR}	_	10	_	ns	1 00 11/14 1000/
Reverse Recovery Charge	Q _{RR}	_	2.6	_	nC	I _F = 9A, dl/dt = 100A/μs

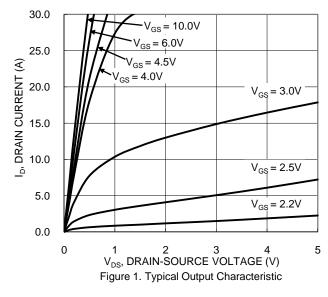
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

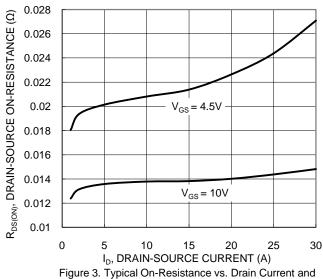
^{6.} Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

 ^{7.} IAS and EAS rating are based on low frequency and duty cycles to keep T_J = +25°C.
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to product testing.

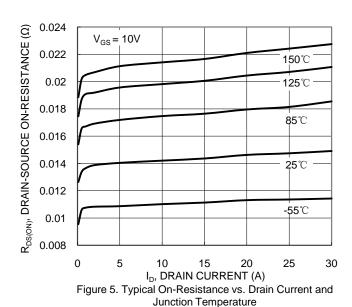


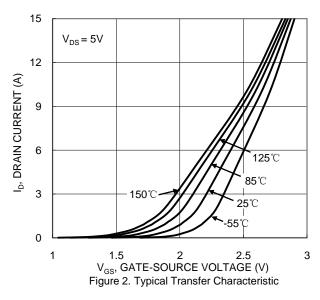


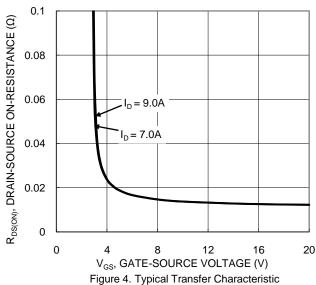




Gate Voltage







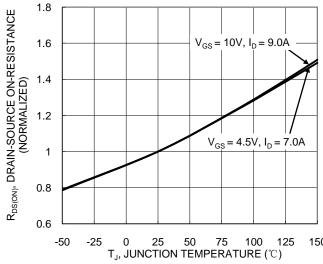


Figure 6. On-Resistance Variation with Junction Temperature



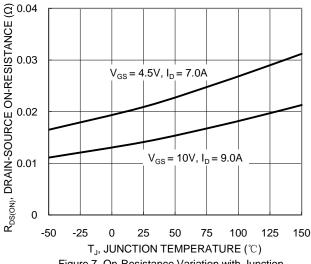
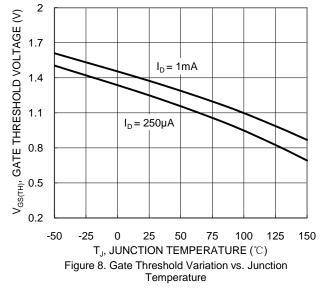
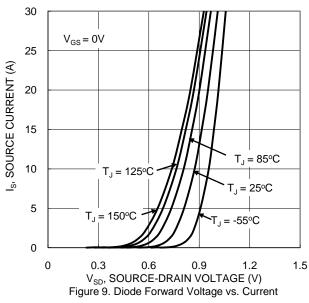
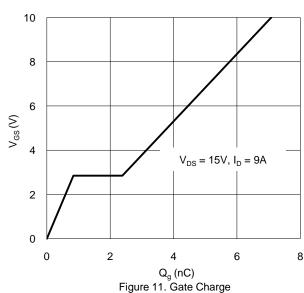
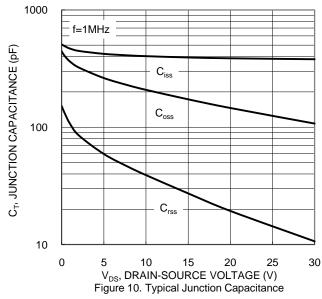


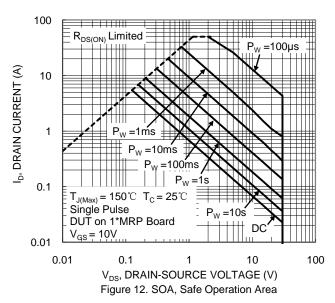
Figure 7. On-Resistance Variation with Junction Temperature













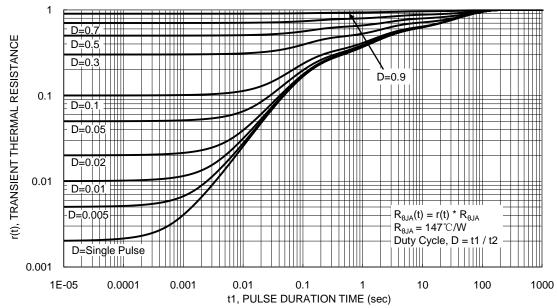


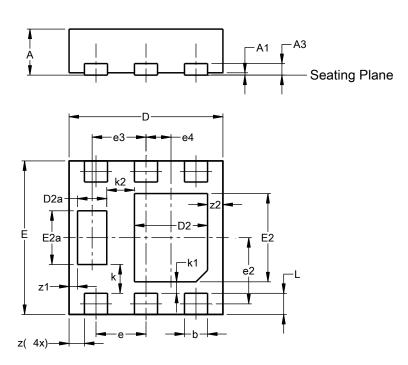
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)

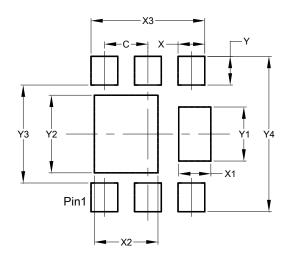


U-DFN2020-6								
(Type F)								
Dim	Min	Тур						
Α	0.57	0.63	0.60					
A1	0.00	0.05	0.03					
А3	-	-	0.15					
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
Е	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
е	0.65 BSC							
e2	C	.863 BS	SC					
е3		0.70 BS						
e4	C	.325 BS	SC					
k	0.37 BSC							
k1	0.15 BSC							
k2	0.36 BSC							
L	0.225 0.325 0.275							
Z		0.20 BS						
z1	C).110 BS	SC					
z2	(0.20 BS	С					
All C	imens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value (in mm)			
С	0.650			
X	0.400			
X1	0.480			
X2	0.950			
Х3	1.700			
Y	0.425			
Y1	0.800			
Y2	1.150			
Y3	1.450			
Y4	2.300			



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